

# **NPN Silicon Transistor**

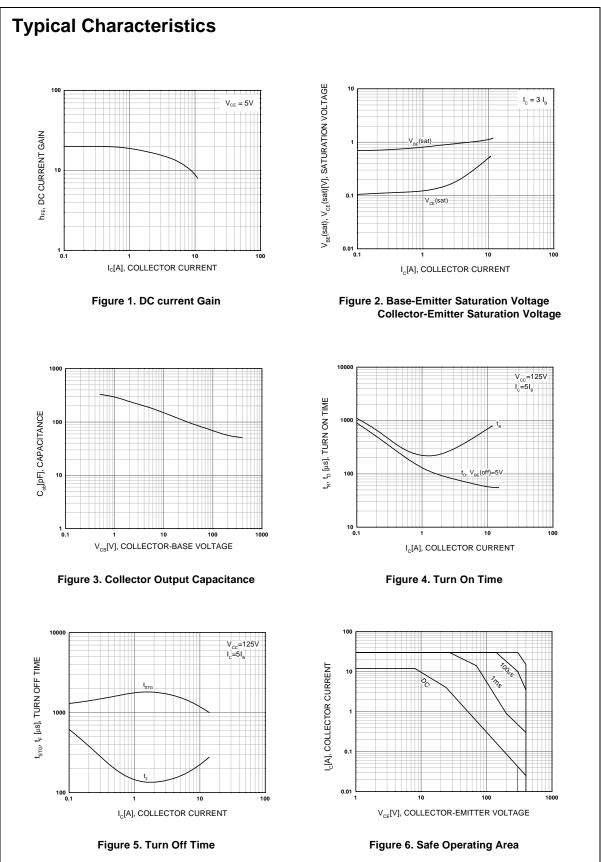
Absolute	Maximum Ratings T <sub>C</sub> =25°C unless otherwise noted	1

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	700	V
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V
V <sub>EBO</sub>	Emitter-Base Voltage	9	V
I <sub>C</sub>	Collector Current (DC)	12	А
I <sub>CP</sub>	Collector Current (Pulse)	24	А
I <sub>B</sub>	Base Current	6	A
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	50	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-65 ~ 150	°C

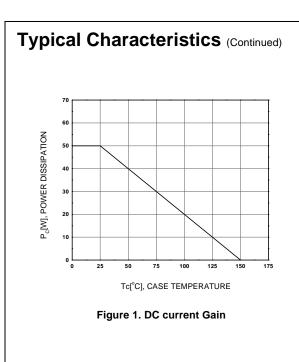
## Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

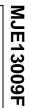
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0	400			V
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 7V, I_{C} = 0$			1	mA
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 5A$	8		40	
		$V_{CE} = 5V, I_{C} = 8A$	6		30	- 5
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_{\rm C} = 5$ A, $I_{\rm B} = 1$ A			1	V
		I <sub>C</sub> = 8A, I <sub>B</sub> = 1.6A		- 7-	1.5	V
		I <sub>C</sub> = 12A, I <sub>B</sub> = 3A	- 1 C	3.3	3	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 5A, I <sub>B</sub> = 1A	1	V West	1.2	V
		$I_{\rm C} = 8A, I_{\rm B} = 1.6A$	-		1.6	V
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 10V$ , f = 0.1MHz		180		pF
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.5A$	4			MHz
t <sub>ON</sub>	Turn ON Time	V <sub>CC</sub> =125V, I <sub>C</sub> = 8A			1.1	μs
t <sub>STG</sub>	Storage Time	$I_{B1} = -I_{B2} = 1.6A$			3	μs
t <sub>F</sub>	Fall Time	$R_L = 15,6\Omega$			0.7	μs

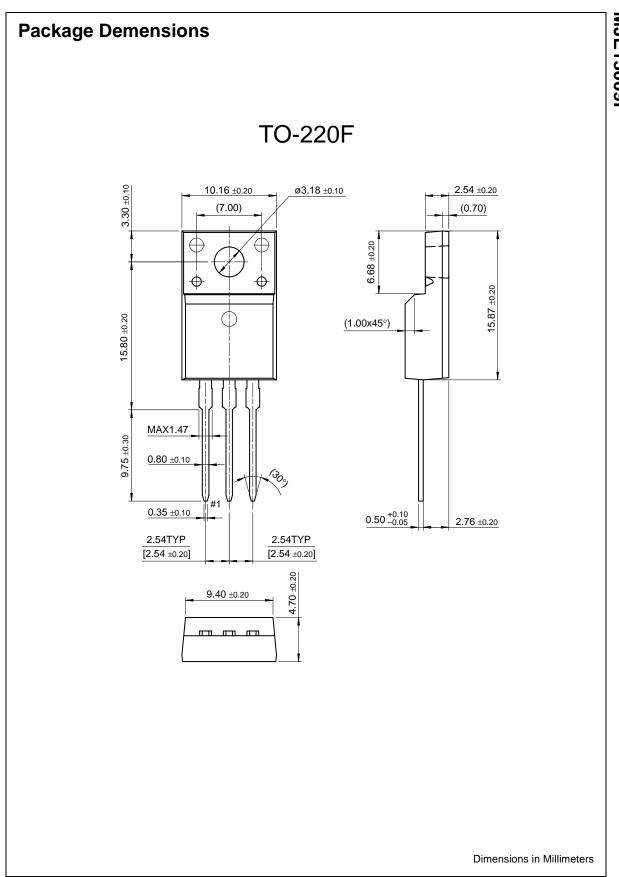
\* Pulse Test: PW≤300μs, Duty Cycle≤2%



MJE13009F







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